2SA1020

One Watt High Current PNP Transistor

ON Semiconductor®

http://onsemi.com

VOLTAGE AND CURRENT ARE NEGATIVE FOR PNP TRANSISTORS

Features

- This is a Pb−Free Device*

MAXIMUM RATINGS

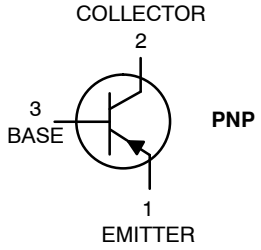
Rating	Symbol	Value	Unit
Collector − Emitter Voltage	V_{CE}	50	Vdc
Collector − Base Voltage	V_{CB}	50	Vdc
Emitter − Base Voltage	V_{EB}	5.0	Vdc
Collector Current − Continuous	I_C	2.0	Adc
Total Power Dissipation @ T_A = 25°C Derate above 25°C	P_D	900 5.0	mW mW/°C
Total Power Dissipation @ T_C = 25°C Derate above 25°C	P_D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	−55 to +150	°C

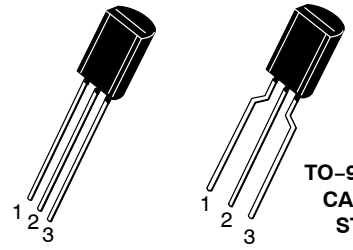
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction−to−Case	$R_{\theta JC}$	83.3	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



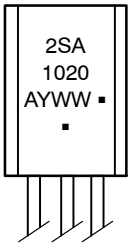


STRAIGHT LEAD
BULK PACK

BENT LEAD
TAPE & REEL
AMMO PACK

TO−92 (TO−226)
CASE 29−10
STYLE 14

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb−Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (Note 1) (I_C = 10 mAdc, I_B = 0)	$V_{(BR)CEO}$	50	–	Vdc
Collector Cutoff Current (V_{CB} = 50 Vdc, I_E = 0)	I_{CBO}	–	1.0	μAdc
Emitter Cutoff Current (V_{EB} = 5.0 V, I_C = 0)	I_{EBO}	–	1.0	μAdc
ON CHARACTERISTICS (Note 2)				
DC Current Gain (I_C = 500 mA, V_{CE} = 2.0 V) (I_C = 1.5 A, V_{CE} = 2.0 V)	h_{FE}	70 40	240 –	–
Collector – Emitter Saturation Voltage (I_C = 1.0 A, I_B = 50 mA)	$V_{CE(sat)}$	–	0.5	Vdc
Base – Emitter Saturation Voltage (I_C = 1.0 A, I_B = 50 mA)	$V_{BE(sat)}$	–	1.2	Vdc
SMALL–SIGNAL CHARACTERISTICS				
Current – Gain – Bandwidth Product (Note 3) (I_C = 500 mAdc, V_{CE} = 2.0 Vdc, f = 100 MHz)	f_T	100	–	MHz

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle = 2.0%.
2. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle = 2.0%.
3. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.

ORDERING INFORMATION

Device	Package	Shipping†
2SA1020RLRAG	TO–92 (Pb–Free)	2000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

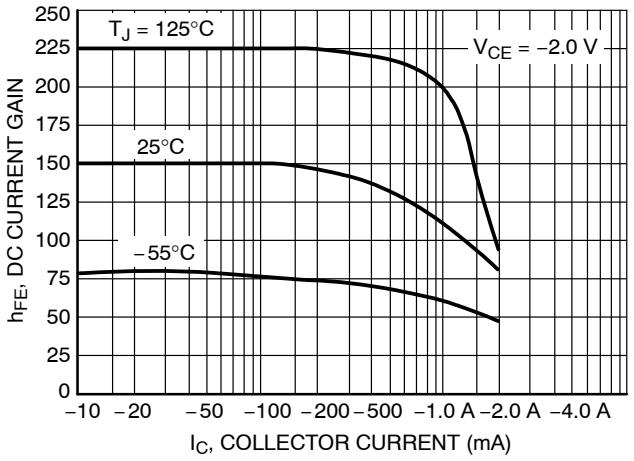


Figure 1. Typical DC Current Gain

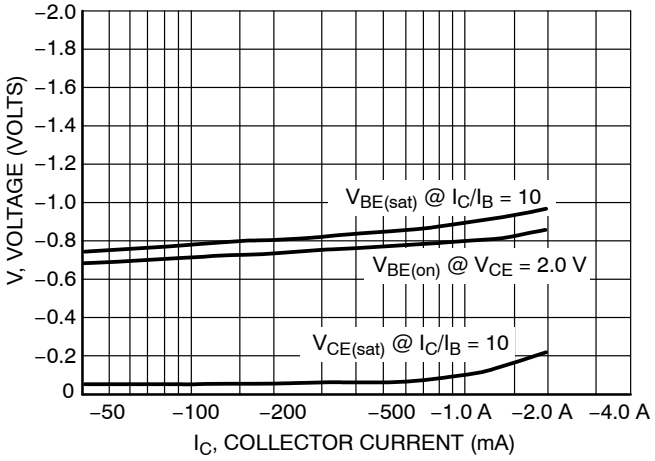


Figure 2. On Voltages

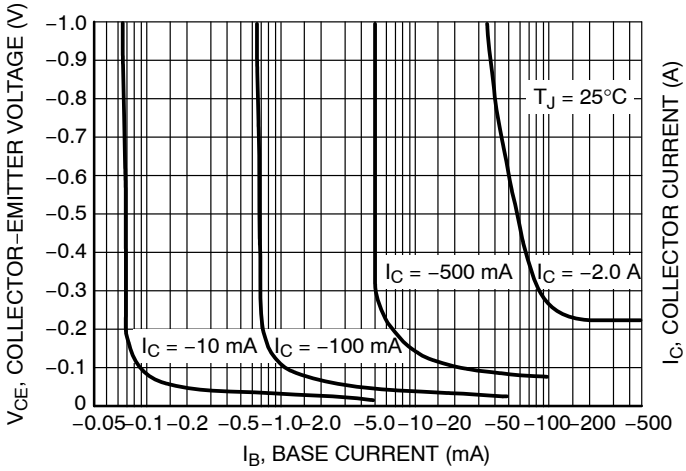


Figure 3. Collector Saturation Region

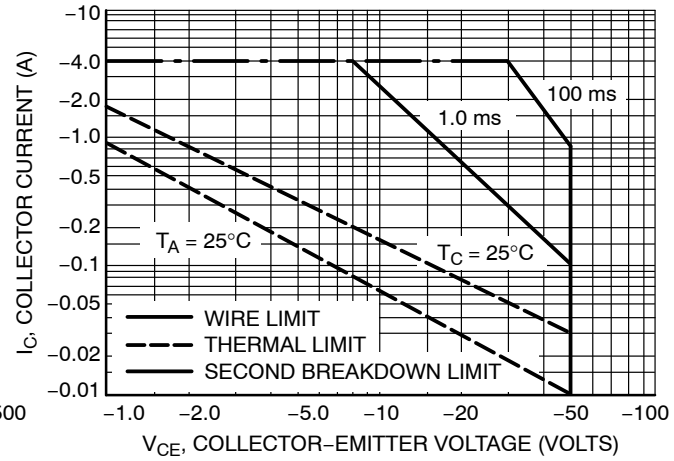
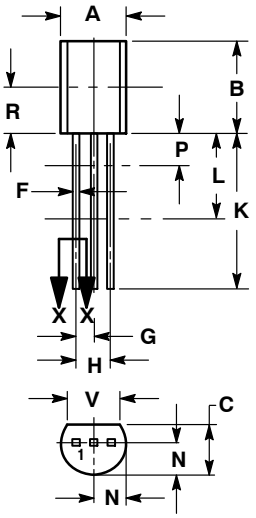


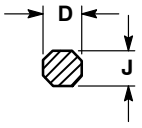
Figure 4. Safe Operating Area

PACKAGE DIMENSIONS

TO−92 (TO−226) 1 WATT
CASE 29−10
ISSUE O



STRAIGHT LEAD
BULK PACK

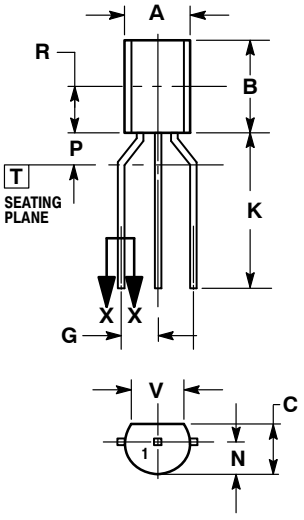


SECTION X−X

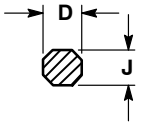
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.44	5.21
B	0.290	0.310	7.37	7.87
C	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.135	---	3.43	---
V	0.135	---	3.43	---

STYLE 14:
PIN 1. EMITTER
2. COLLECTOR
3. BASE



BENT LEAD
TAPE & REEL
AMMO PACK



SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
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3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
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C	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
G	0.094	0.102	2.40	2.80
J	0.018	0.024	0.46	0.61
K	0.500	---	12.70	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.135	---	3.43	---
V	0.135	---	3.43	---

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